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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT: Martin Czech et al.

GROUP: 2811

SERIAL NO: 09/780,976

EXAMINER: Steven Lok

FILED: February 9, 2001

FOR: LATERAL THYRISTOR STRUCTURE FOR PROTECTION
AGAINST ELECTROSTATIC DISCHARGE

Honorable Commissioner of Patents
and Trademarks
Washington, D.C. 20231

Sir:

AMENDMENT

This amendment is in response to the Official Action dated June 18, 2002.

Please amend the application as follows:

IN THE CLAIMS:

✓ Cancel claim 7.

Amend claims 1-3, 6 and 8-12 as follows:

5th *82*
1. (amended) A lateral thyristor structure for protection against electrostatic discharge,
comprising:

at least two lateral thyristors, which each include

a semiconductor substrate of a first conduction type, with a surface;

a well region of a second conduction type, opposite to said first conduction type,

which is introduced into said surface of said semiconductor substrate;